

## Features

- Low On-Resistance
- Ideal for Notebook Computer, Portable Phone, PCMCIA Cards, and Battery Power Circuits
- **Lead Free By Design/RoHS Compliant (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **ESD Protected Gate**
- **"Green" Device (Note 3)**



ESD protected

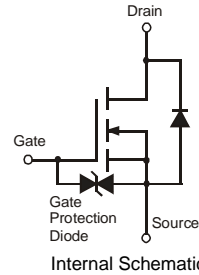


TOP VIEW

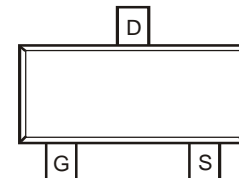
SC-59

## Mechanical Data

- Case: SC-59
- Case Material - Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.008 grams (approximate)



Internal Schematic



TOP VIEW

## Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	20	V
Gate-Source Voltage	V <sub>GSS</sub>	±12	V
Drain Current	I <sub>D</sub>	Continuous	1.2
		Pulsed	4.0

## Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation	P <sub>d</sub>	500	mW
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	250	°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 1)</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	10	μA	@ T <sub>j</sub> = 25°C V <sub>DS</sub> = 24V, V <sub>GS</sub> = 0V
Gate-Body Leakage	I <sub>GSS</sub>	—	—	±10	μA	V <sub>GS</sub> = ±12V, V <sub>DS</sub> = 0V
<b>ON CHARACTERISTICS (Note 1)</b>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.7	—	1.40	V	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1.0mA
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	—	0.100	Ω	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 0.5A V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 0.5A
		—	—	0.160		
Forward Transfer Admittance	Y <sub>fs</sub>	—	3.3	—	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.5A
Diode Forward Voltage	V <sub>SD</sub>	—	0.8	1.1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1.0A
<b>DYNAMIC CHARACTERISTICS</b>						
Input Capacitance	C <sub>ISS</sub>	—	180	—	pF	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1.0MHz
Output Capacitance	C <sub>OSS</sub>	—	120	—	pF	
Reverse Transfer Capacitance	C <sub>RSS</sub>	—	45	—	pF	
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Delay Time	t <sub>D(ON)</sub>	—	10	—	ns	V <sub>DD</sub> = 10V, I <sub>D</sub> = 0.5A, V <sub>GS</sub> = 5.0V, R <sub>GEN</sub> = 50Ω
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	50	—	ns	
Turn-On Rise Time	t <sub>r</sub>	—	15	—	ns	
Turn-Off Fall Time	t <sub>f</sub>	—	45	—	ns	

- Notes:
1. Pulse width ≤300μs, duty cycle ≤2%.
  2. No purposefully added lead.
  3. Diodes Inc's "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).

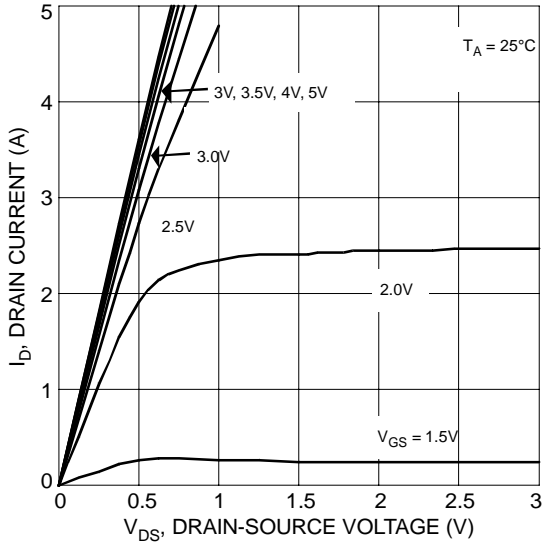


Fig. 1 Typical Output Characteristics

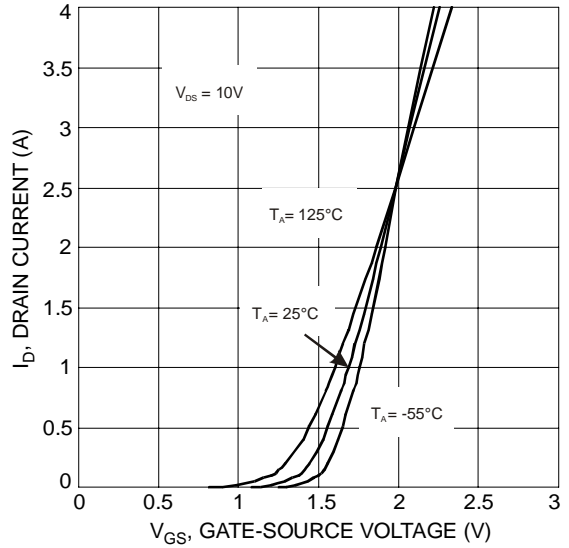


Fig. 2 Typical Transfer Characteristics

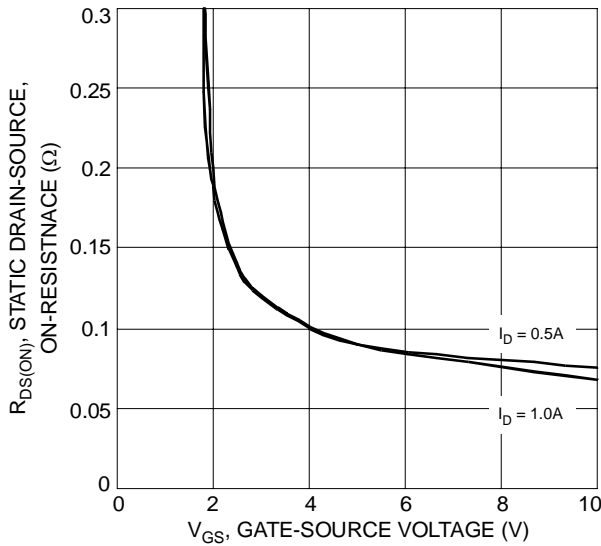


Fig. 3 On-Resistance vs. Gate Voltage

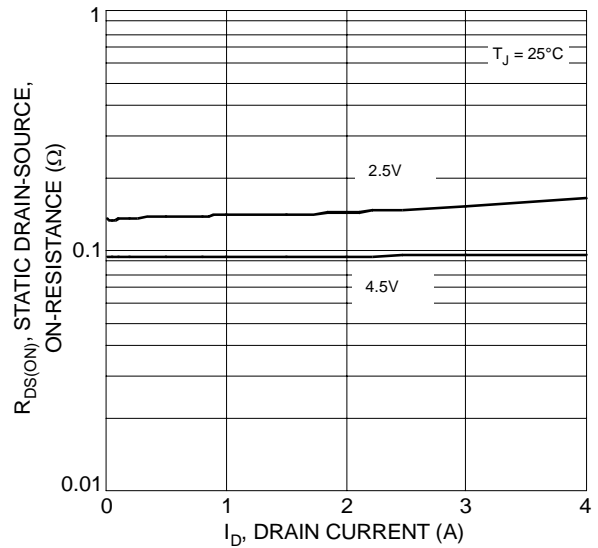


Fig. 4 On-Resistance vs. Drain Current

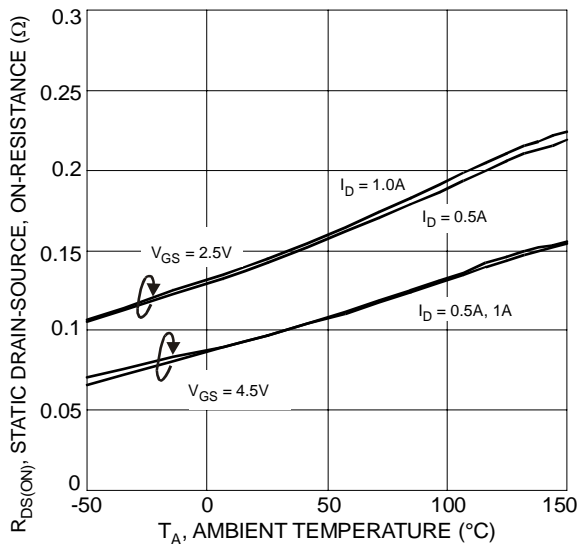


Fig. 5 On-Resistance Variation with Temperature

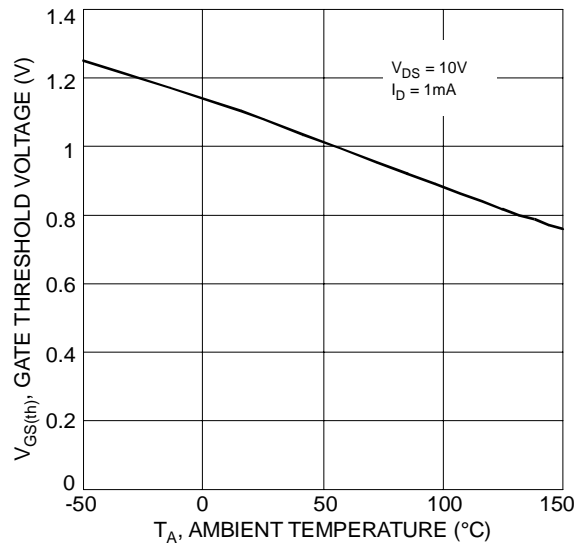


Fig. 6 Gate Threshold Voltage vs. Temperature

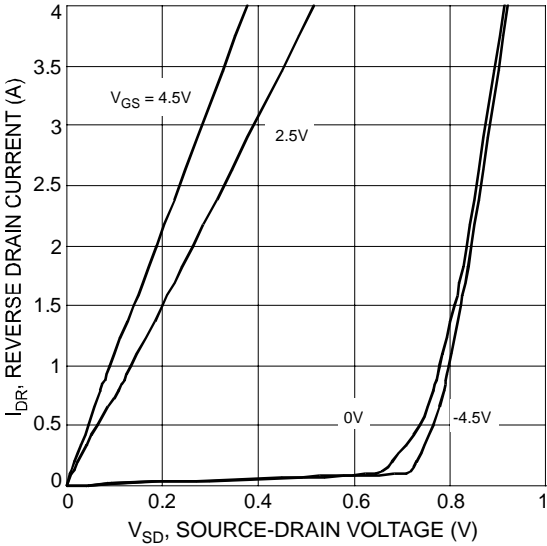


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

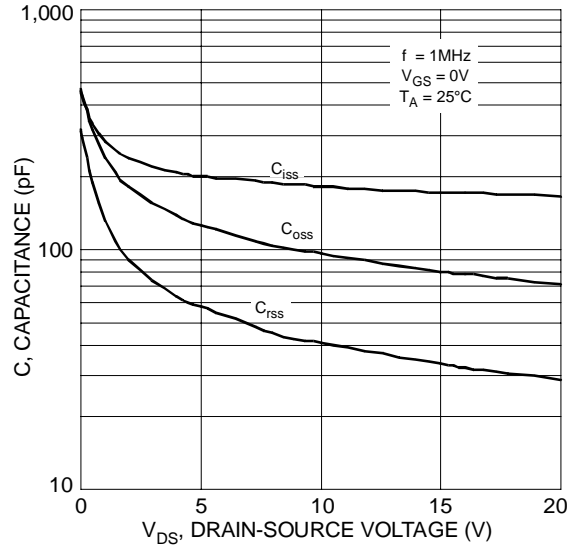


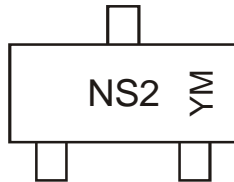
Fig. 8 Typical Total Capacitance

**Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN2114SN-7	SC-59	3000/Tape & Reel

Notes: 4. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**



NS2 = Product Type Marking Code  
YM = Date Code Marking  
Y = Year ex: T = 2006  
M = Month ex: 9 = September

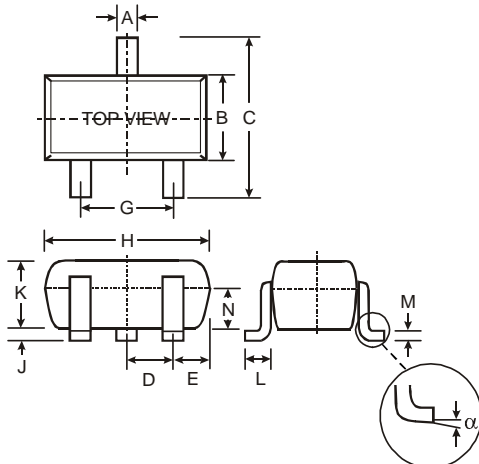
Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012
Code	T	U	V	W	X	Y	Z

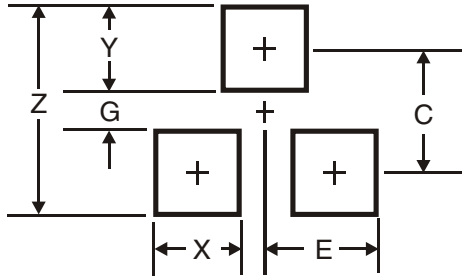
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Package Outline Dimensions**



SC-59		
Dim	Min	Max
A	0.35	0.50
B	1.50	1.70
C	2.70	3.00
D	0.95	
E	—	
G	1.90	
H	2.90	3.10
J	0.013	0.10
K	1.00	1.30
L	0.35	0.55
M	0.10	0.20
N	0.70	0.80
α	0°	8°
All Dimensions in mm		

**Suggested Pad Layout**



Dimensions	Value (in mm)
Z	4.0
G	1.2
X	0.9
Y	1.4
C	2.6
E	0.95

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